

High gain Low Voltage PNP power transistor

Features

- Very low Collector to Emitter saturation voltage
- D.C. Current gain, $h_{FE} > 100$
- 1.5 A continuous collector current

Applications

- Power management in portable equipment
- Switching regulator in battery charger applications

Description

The device is a PNP transistor manufactured using new "PB-HDC" (Power Bipolar High Density Current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

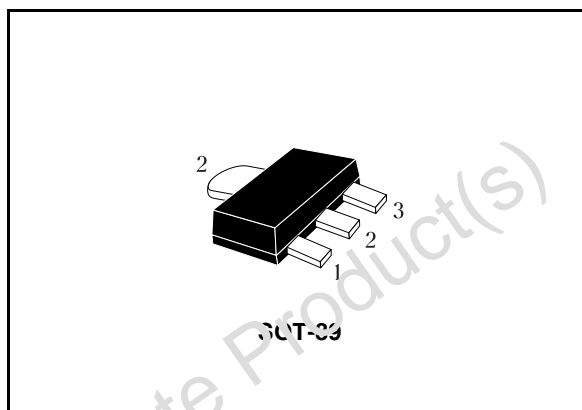


Figure 1. Internal schematic diagram

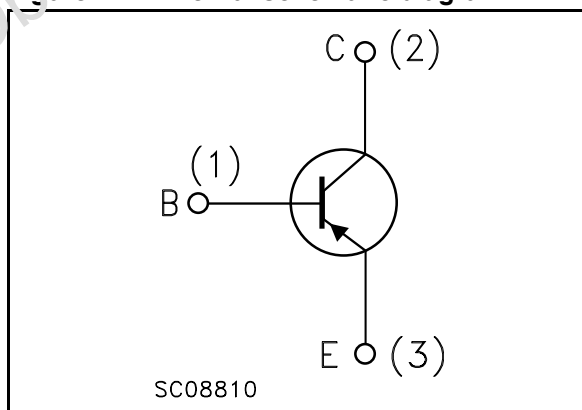


Table 1. Device summary

Order code	Marking	Package	Packaging
2STF2220	2220	SOT-89	Tape & reel

Contents

1	Electrical ratings	3
2	Electrical characteristics	4
2.1	Electrical characteristics (curves)	5
2.2	Test circuits	7
3	Package mechanical data	8
4	Revision history	10

Obsolete Product(s) - Obsolete Product(s)

1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage ($I_E = 0$)	-20	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	-20	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	-5	V
I_C	Collector current	-1.5	A
I_{CM}	Collector peak current ($t_P < 5\text{ms}$)	-3	A
I_B	Base current	-0.1	A
I_{BM}	Base peak current ($t_P < 5\text{ms}$)	-0.2	A
P_{tot}	Total dissipation at $T_{amb} = 25^\circ\text{C}$	1.4	W
T_{stg}	Storage temperature	-65 to 150	$^\circ\text{C}$
T_J	Max. operating junction temperature	150	$^\circ\text{C}$

Table 3. Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-amb}^{(1)}$	Thermal resistance junction-amb max	89	$^\circ\text{C}/\text{W}$

(1) Device mounted on PCB area of 1cm^2

2 Electrical characteristics

($T_{\text{case}} = 25^{\circ}\text{C}$ unless otherwise specified)

Table 4. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current ($I_{\text{E}} = 0$)	$V_{\text{CB}} = -20\text{V}$			-0.1	μA
I_{EBO}	Emitter cut-off current ($I_{\text{C}} = 0$)	$V_{\text{EB}} = -5\text{V}$			-0.1	μA
$V_{(\text{BR})\text{CEO}}^{(2)}$	Collector-emitter breakdown voltage ($I_{\text{B}} = 0$)	$I_{\text{C}} = -10\text{mA}$	-20			V
$V_{(\text{BR})\text{EBO}}$	Emitter-base breakdown voltage ($I_{\text{C}} = 0$)	$I_{\text{E}} = -100\mu\text{A}$	-5			V
$V_{\text{CE}(\text{sat})}^{(2)}$	Collector-emitter saturation voltage	$I_{\text{C}} = -0.5\text{A}$ $I_{\text{B}} = -50\text{mA}$ $I_{\text{C}} = -1.5\text{A}$ $I_{\text{B}} = -150\text{mA}$			-0.25 -0.45	V V
$V_{\text{BE}(\text{sat})}^{(2)}$	Base-emitter saturation voltage	$I_{\text{C}} = -0.5\text{A}$ $I_{\text{B}} = -50\text{mA}$ $I_{\text{C}} = -1.5\text{A}$ $I_{\text{B}} = -150\text{mA}$			-1 -1.1	V V
$V_{\text{BE}(\text{on})}^{(2)}$	Base-emitter on voltage	$I_{\text{C}} = -1\text{A}$ $V_{\text{CE}} = -2\text{V}$			-1	V
$h_{\text{FE}}^{(2)}$	DC current gain	$I_{\text{C}} = -100\text{mA}$ $V_{\text{CE}} = -2\text{V}$ $I_{\text{C}} = -500\text{mA}$ $V_{\text{CE}} = -2\text{V}$ $I_{\text{C}} = -1.5\text{A}$ $V_{\text{CE}} = -2\text{V}$ $I_{\text{C}} = -3\text{A}$ $V_{\text{CE}} = -2\text{V}$	200 170 120 75		600	
C_{CBQ}	Collector-base capacitance	$I_{\text{E}} = 0$ $V_{\text{CB}} = -10\text{V}$ $f = 1\text{MHz}$		30		pF
t_{on}	Resistive load Turn-on time	$I_{\text{C}} = -1.5\text{A}$ $V_{\text{CC}} = -10\text{V}$		60		ns
t_{off}	Turn-off time	$I_{\text{B}1} = -I_{\text{B}2} = -150\text{mA}$		250		ns

Note (2) Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. Output characteristics

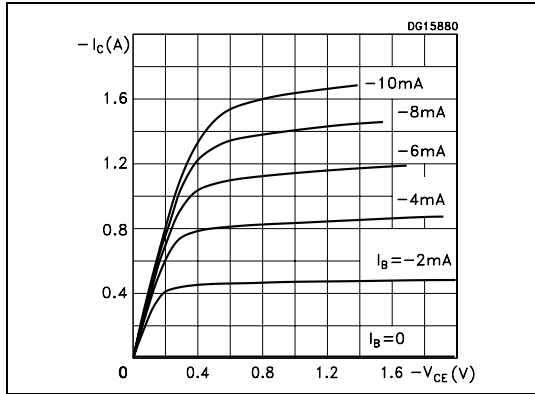


Figure 3. Derating curve

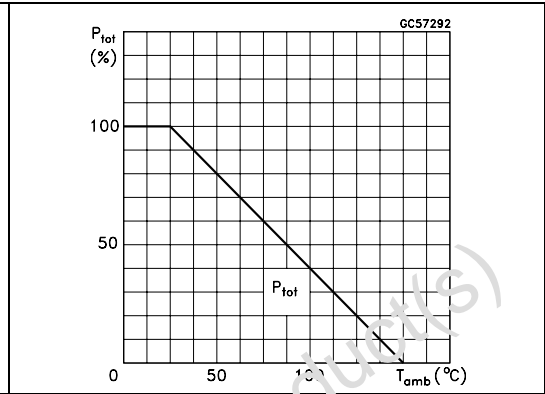


Figure 4. DC current gain

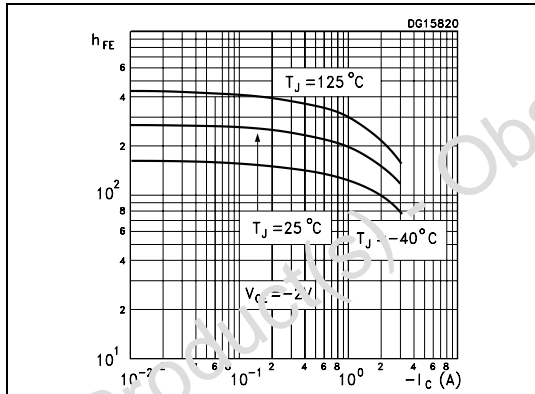


Figure 5. DC current gain

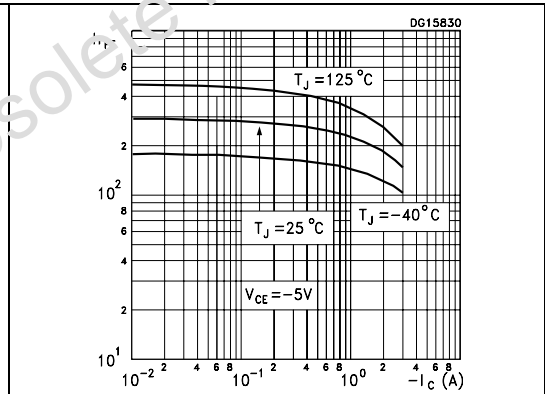


Figure 6. Collector-emitter saturation voltage

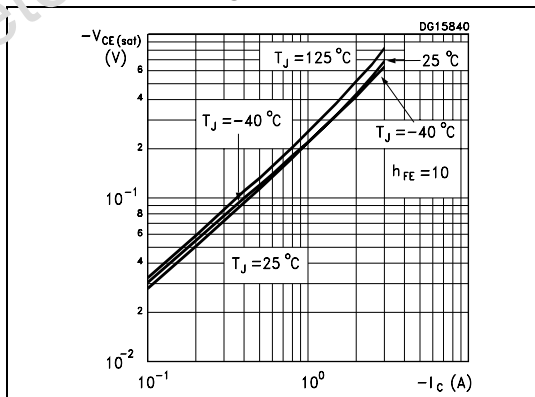


Figure 7. Base-emitter saturation voltage

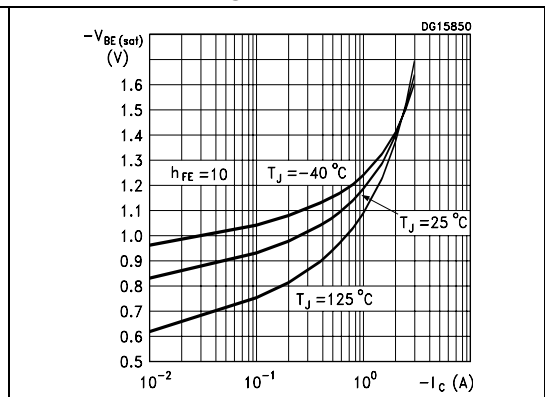


Figure 8. Base-emitter on voltage

Figure 9. Capacitance curves

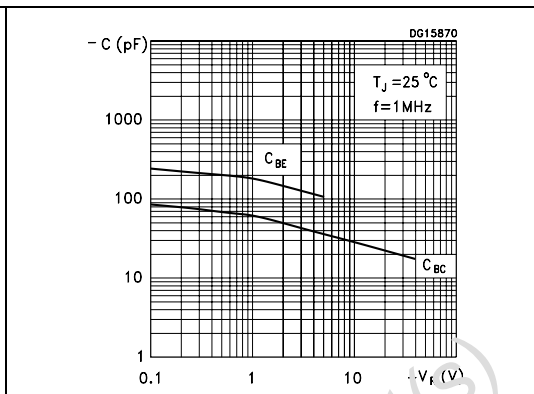
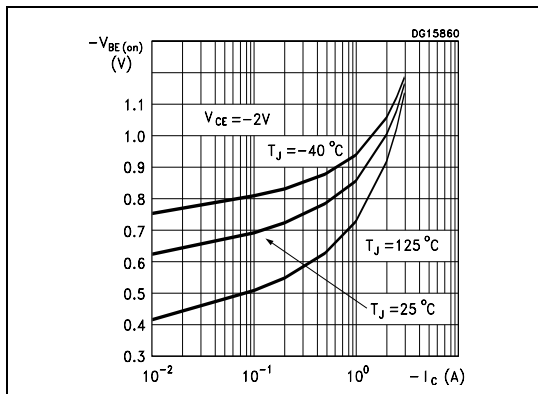
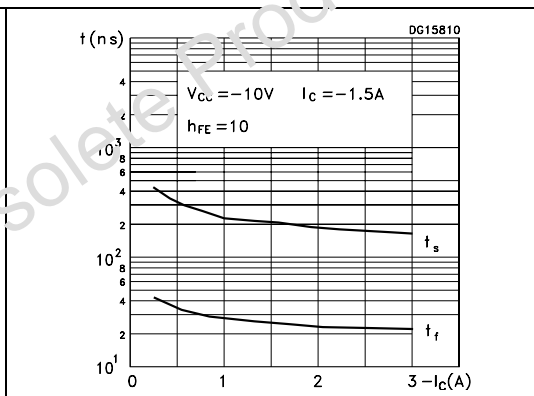
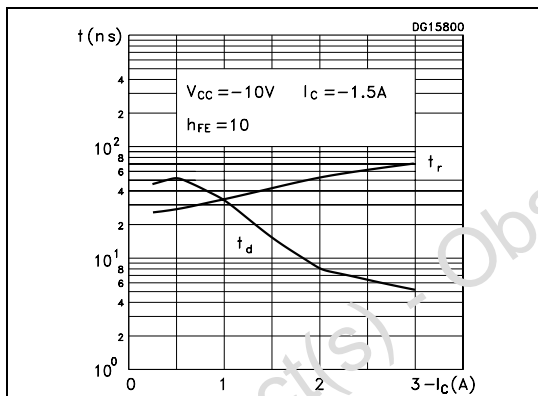


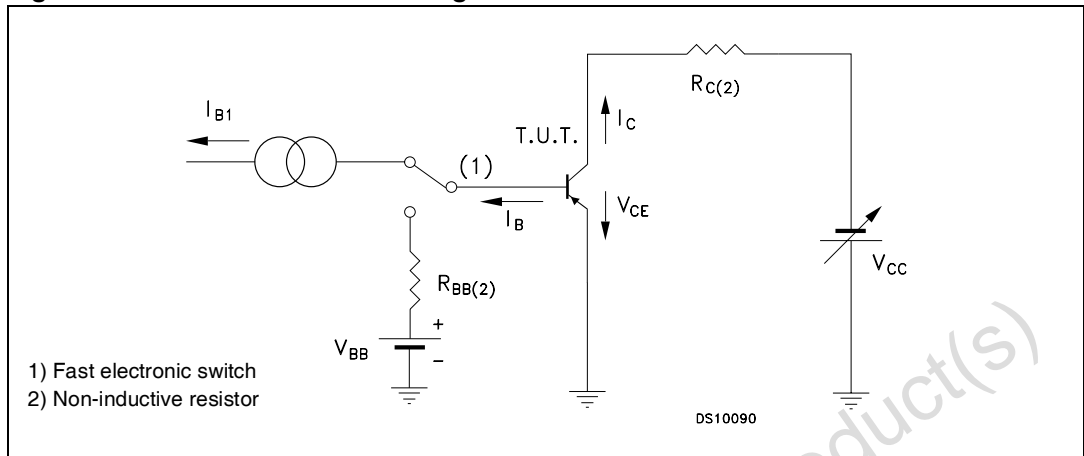
Figure 10. Switching time resistive load

Figure 11. Switching time resistive load



2.2 Test circuits

Figure 12. Resistive load switching test circuit



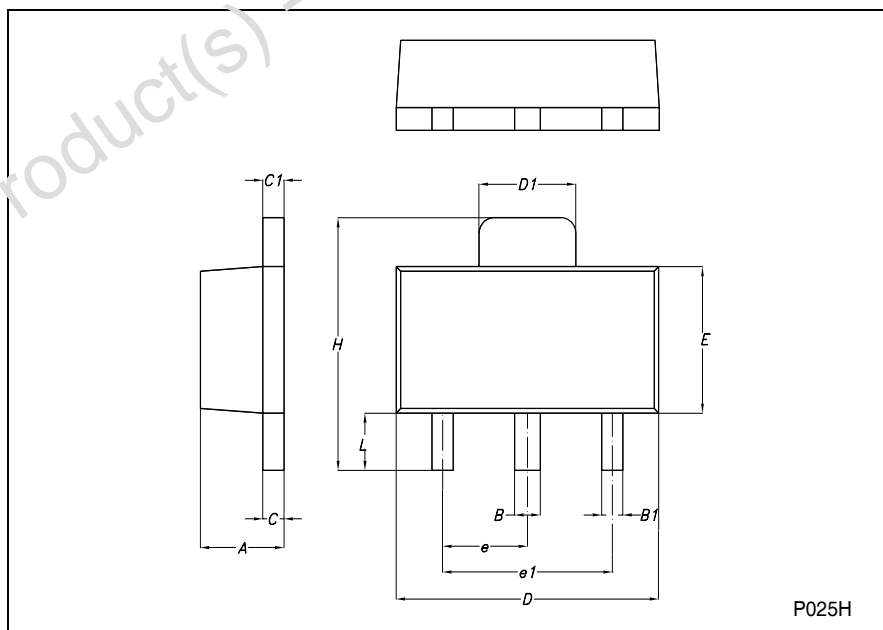
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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SOT-89 MECHANICAL DATA

DIM.	mm			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	1.4		1.6	55.1		63.0
B	0.44		0.56	17.3		22.0
B1	0.36		0.48	14.2		18.9
C	0.35		0.44	13.8		17.3
C1	0.35		0.44	13.8		17.3
D	4.4		4.6	173.2		181.1
D1	1.62		1.83	63.8		72.0
E	2.29		2.6	90.2		102.4
e	1.42		1.57	55.9		61.8
e1	2.92		3.07	115.0		120.9
H	3.94		4.25	155.1		167.3
L	0.89		1.2	35.0		47.2



P025H

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
19-Jun-2006	1	Initial release.
27-Sep-2006	2	New maturity code.
18-Sep-2007	3	Added Figure 3 .

Obsolete Product(s) - Obsolete Product(s)

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